M etallic m ean-eld stripes, incom m ensurability and chem ical potential in cuprates

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W e perform a system atic slave-boson m ean-eld analysis of the three-band m odel for cuprates with rst-principle parameters. C ontrary to widespread believe based on earlier m ean-eld computations low doping stripes have a linear density close to 1/2 added hole per lattice constant. We nd a dimensional crossover from 1D to 2D at doping 0:1 followed by a breaking of particle-hole sym m etry around doping 1/8 as doping increases. O ur results explain in a simple way the behavior of the chem ical potential, the m agnetic incom m ensurability, and transport experiments as a function of doping. B ond centered and site-centered stripes becom e degenerate for sm all overdoping.

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It is now a well established fact that doped holes in cuprates tend to self-organize in antiferrom agnetic (AF) dom ain walls[1, 2, 3, 4, 5]. These quasi one-dimensional (1D) structures called stripes where predicted by mean-

eld theories [6, 7] inspired by the problem of solitons in conducting polymers [8].

In the superconducting systems observed stripes are parallel to the Cu-O bond (hereafter called vertical stripes) and for low doping have a linear lling fraction

1=2 of added holes per lattice constant (a 1). Unless a one-dimensional (1D) instability opens a gap at the Ferm i level[9], half-lled (= 1=2) stripes are expected to be metallic. On the contrary mean-eld theories predicted = 1 insulating stripes which led to an early rejection of stripes[10].

Here we perform a system atic analysis of slave-boson (SB) mean- eld [11] solutions for a three-band Hubbard model as appropriate for the cuprates. Contrary to the early mean- eld analysis we nd that for low doping x in a material like $La_{2 x} Sr_x CuO_4$ (LSCO) the most favorable stripes have indeed 1=2 (and are vertical) reconciling the mean- eld picture with experiment. Small doping introduces more stripes at xed reducing the stripe distance d and explaining the observed behavior of the magnetic incommensurability x with

= 1 = (2d) [1, 2, 3, 4, 5].

We nd low doping stripes to be centered on oxygen, bridging two Cu sites, hereafter named bond centered (BC) stripes after the term inology of one-band models[12, 13] (see Fig. 1).

Signi cant interstripe overlap sets in at x = 0.1 triggering a crossover from 1D behavior at low doping to 2D behavior at large doping. This does not a left the stability of stripes up to x = 1=8 where a change of regime occurs. Further doping occurs at a left xed stripe distance d = 4 and

starts to grow. This explains the change of behavior observed in both the incommensurability [2, 3, 4, 5] and the chemical potential [14, 15] around doping x = 1=8. Furthermore for x < 1=8 the chemical potential is at the center of an approximately particle-hole symmetric

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FIG.1: BC vertical stripe with d = 7 and = 1=2 (x = 1=14). Sites with (without) arrows are Cu (0). The length of the arrows is proportional to the local magnetization on Cu (negligibly on 0). The radius of the circle represent the excess charge respect to the AF state (0.09 holes for the largest one). The y axis is taken on the stripe direction (vertical). The picture repeats periodically in x and y directions

band (Fig. 2) whereas for doping x > 1=8 particle-hole sym m etry is broken in good agreem ent with the picture deduced from transport experim ents[16, 17]. Finally at x = 0.21 BC stripes and site-centered (SC) stripes becom e degenerate suggesting a regim e of soft lateral stripe

uctuations possibly relevant for superconductivity. This quasidegeneracy was found in more sophisticated treatm ents of (less realistic) one-band models[12, 13] how ever the ordering of the states was reversed [13].

O ne-band m odels can provide qualitative understanding but m ay m iss subtle but important details speci c for the cuprates. Therefore we use a three-band Hubbard model with a parameter set deduced from a rstprinciple LDA computation for LSCO [18]. We view our com putation as the last stage of a st principle com putation and thus without free parameters. The largest repulsion U_d [18] is treated within a SB approach [11] fully equivalent to the Gutzwiller approximation and the other interactions are treated within the Hartree-Fock (HF) approximation (an equivalent formalism has been used in Ref. [19] for electron-doped cuprates). We solve the mean-eld equations both in real and in momentum space. The real space computations are completely unrestricted [20] except for the spins which are assumed to be along the z axis.

Typically wem in in ize the energy in large clusters with

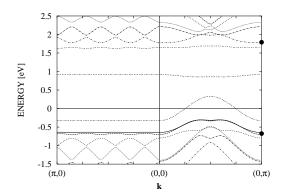


FIG. 2: Electron mean-eld bands for the stripe of Fig. 1 measured from the chemical potential. Left (right) panel is in the direction perpendicular (parallel) to the stripe. We also plot the insulating charge transfer gap at momentum k = (0;) measured from the same reference energy (dots).

 N_s stripes ($N_s = 2;4$) of a maximum length L = 30. Depending on boundary conditions, size and lling, solutions with and without charge order in the stripe direction are obtained. In general due to the 1D character of stripes one expects that a 1D instability will develop in large system s at low doping rendering the system insulating even for < 1. Indeed if superconductivity is suppressed by pulsed magnetic elds the system is insulating below a critical doping and a crossover temperature T [21]. In this work for simplicity we concentrate on the metallic state and restrict to solutions without charge order in the stripe direction. Since T is quite sm all compared with the typical electronic scales we can set the temperature to zero in our computations.

Fig. 1 depicts the typical charge and spin distribution for a BC vertical stripe. Added charge is accumulated in the antiphase boundary between the AF regions and mainly resides on oxygen sites.

In Fig.2 we show the band structure for the electrons in an extended zone scheme. Two bands appear well inside the charge transfer gap. The upper one at 0.9 eVis more Cu like and quite at (even in the stripe direction) whereas the lower one has substantial dispersion, is mainly 0 like, and crosses the Ferm i level. Counting both ingap bands the = 1=2 system corresponds to 3=4 hole (1=4 electron) band lling. The gap between the bands is related to the magnetic character of the stripe. (It is absent in SC solutions with a non-magnetic core.) The electronic structure close to the chemical potential is well represented by a half-lled cosine like band, hereafter referred to as the active band.

The dispersion of the active band perpendicular to the stripe is quite at indicating quasi 1D behavior. Sm all oscillations appear in this direction for d 5 which can be identieed as a crossover interstripe distance from 1D to 2D behavior and corresponds to a crossover doping x = 0.1 for x = 0.5.

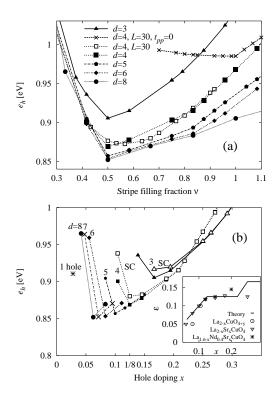


FIG.3: e_h as a function of (a) and x (b) for vertical BC stripes. Sizes are 4d 12 ford 6 and 2d 12 ford > 6. In (a) we also show the result for 4d 30 (open squares) and setting $t_{pp} = 0$ shifted down by 0.89 eV (crosses). In (b) we also show the result for site-centered stripes (labeled SC, open sym bols) for d = 3;4 and one self-trapped hole or \electronic polaron" at x = 1=36. The inset in (b) reports the incom m ensurability as obtained from the present calculation (line) com pared with experim ental data from Ref. [3].

The band structure in the stripe direction (right panel) is quite similar in all BC stripes solutions regardless of d which instead determ ines the periodicity in the perpendicular direction (left panel). Comparison with photoem ission data requires matrix elements considerations and will be presented elsewhere. Here we notice that the Ferm i surface crossing at vertical momentum $k_y = 4$ has been recently observed for d = 4 stripes[22] and the

at portion of the active band in the direction perpendicular to the stripe correlates well with the at bands observed in many cuprates around k (;0)[23].

To evaluate the stability we compute the energy per added hole for N_h holes added to the system with N CuO₂ units, e_h $\mathbb{E}(\mathbb{N} + \mathbb{N}_h) = (\mathbb{N}) = \mathbb{N}_h$. Here $\mathbb{E}(\mathbb{N} + \mathbb{N}_h) = (\mathbb{N})$ is the total energy of the doped [undoped AF] solution. In Fig. 3 (a) we show e_h as a function of the lling fraction $\mathbb{N}_h = (\mathbb{N}_s L)$ for BC vertical stripes. Each curve corresponds to a xed d. The curves have a sharp m inim um at = 0.5. This is in contrast to early one-band [7, 9] and three-band m ean-eld com putations[6] for which = 1 is the most favorable hole lling. We can reproduce this behavior by setting arti cially $\frac{1}{2}p_p = 0$ in our parameter set (crosses). The di erence in behavior can be understood by analyzing the band structure. In the case $t_{pp} = 0$ the active band becom es as narrow as the 0.9eV band (Fig. 2) and a gap develops between the active band and the band immediately bellow instead of overlapping as in Fig. 2. This gap produces the cusp singularity at = 1 [Fig. 3 (a)]via the discontinuity in QE = QN which makes = 1 very stable. As tpp is increased the gap closes, the cusp singularity disappears, and a minimum develops in the < 1part of the curve. A simple model explains the form ation of this minimum. Consider a at density of states (DOS) of width W to estimate the kinetic energy of the active band and neglect interactions. In this approxim ation $e_h = e_0 = + W = 2$ where e_0 is the energy cost per unit length to create a dom ain wall in the undoped system (e₀ J=2 with J the superexchange constant). The lling is given by $v_{pt} = m in (2e_0 = W; 1)$. Inoptim um creasing t_{pp} increases W without substantially a ecting e_0 and produces a local minimum for < 1. The stability close to = 1=2 is further enhanced because the DOS of a 1D band is not at but has a minimum at = 1=2. For the same reason a gap produces a cusp in the energy, a minimum of the DOS enhances the local curvature of and tends to shift the optim um lling closer to e_h vs. = 1=2.

W e have checked that for the m ost com m on param eter sets which contain t_{pp} [18] results are similar. However, as soon as t_{pp} is set to zero, as in R ef. [6], half-lled stripes become unstable in favor of lled ones.

The $t_{pp} = 0$ result is in accord with HF computations in the simplest one-band model. Including a secondneighbor hopping (t⁰) we have found that partially led stripes can be stabilized also in one-band models by a similar mechanism, which will be reported elsewhere.

Partially led stripes where also found in the one-band H ubbard m odel with $t^0 = 0$ in a much stronger correlation regime and going beyond a static mean-eld[13]. In our case, because the active band is broad, correlations are less in portant and we expect that a static mean-eld provides a good starting point.

Vertical stripes should be compared with other possible ground states. We nd that within the present SB approach they are lower in energy than polaron solutions[24] [see Fig. 3 (b)] and diagonal stripes solutions (not shown). Very low nonsuperconducting dopings (x < 0.05) were not explored in detail since we believe that a careful consideration of other e ects is required in this case. E specially long-range order perpendicular to the planes favors loop con gurations of stripes[12] and long-range C oulom b e ects[25, 26] are expected to becom e in portant.

If one uses the HF approximation instead of SB the minimum also occurs at 1=2 for BC vertical stripes. However a polaron lattice is the ground state in HF and diagonal stripes are lower in energy than vertical ones. Thus the overall success of the present m ean - eld com - putation w ith respect to the earlier ones[6] is due to both a more accurate <math>m ean - eld approximation SB instead of HF) and a more accurate parameter set.

Further stabilization of the half-led stripes can occur if due to many-body e ects a gap or pseudogap tends to open at the commensurate lling = 1=2[9]. Although we do not need this e ect to explain 1=2 it is quite possible that this produces a netuning for T < T. In this regard it is interesting to remark that the \V " shape form of the curves in Fig. 3 (a) is due to the gap produced by the discretization of the levels in a nite system. For larger systems [see d = 4 curve in Fig. 3 (a)] the cusp becom es rounded, how ever the minimum is still close to

= 1=2. One should be aware that the curves with the cusp are for already quite long stripes (L = 12) and it is not clear whether stripes in realm aterials will be much longer. Thus nite size data could turn out to be more realistic than in nite size one.

For d > 4 all curves coincide close to = 0.5 in Fig. 3 (a) whereas for d = 3;4 the curves are shifted up. This feature is due to the width of the dom ain wall of 4 5 lattice sites (see Fig. 1) which forces stripes to overlap leading to an increase of e_h .

In Fig. 3 (b) we show e_h for various values of the stripe separation d and as a function of doping x assuming each dopant introduces one hole. Since x = -d curves with larger d appear at low er concentration. The locus of the m in im um of en as a function of doping in Fig. 3 (b) is expected to form a continuous curve in the therm odynam ic lim it by combining di erent d solutions in new solutions with larger periodicity. Up to x 1=8 the stripe 11ing is xed at 0:5 and consequently the density of stripes increases with doping. This explains the behavior of the incom mensurability = x=(2)x as seen in neutron scattering experim ents in this doping range (inset of Fig. 3) [1, 2, 3, 4, 5]. For x > 1=8 the right branch of the d = 4 solution is more stable than the 0:5 and d = 3 solution due to the stripe overlap e ect. Therefore the incom m ensurability rem ains locked at 1=8 in good agreem ent with the change of behavior in observed around x 1=8[2, 3, 4, 5].

As doping increases further, BC stripes become degenerate with SC ones at x = 0.21. This suggests that as doping increases lateral uctuations of the stripe will become soft and possibly mediate pairing between holes.

For doping x > 0.225 we nd the d = 3 stripe (= 1=6 0.17) to become the lowest energy solution with an initial lling fraction = 0.675. Experimentally the situation is not clear. = 1=6 has been reported for YBa₂Cu₃O₆₊ [5] (YBCO) but not for LSCO where remains in the = 1=8 line up to x = 0.25 (inset of Fig. 3). In La_{2 x y} Nd_ySr_xCuO₄ (LNSCO), where stripes are pinned by the low-tem perature tetragonal lattice distortion, the incommensurability is substantially increased beyond = 1=8 at doping x = 0.2 but without It is possible that lateral stripe uctuations become so strong at this doping range that an electively isotropic state is reached [27]. Another possibility is that the d = 3 phase is skipped due to phase separation among the d = 4 phase and the overdoped Fermi liquid which for our parameters becomes the lowest energy solution close to x = 0.4 (see Ref. [28] for a related scenario). Further theoretical and experimental work should be done to clarify this point. Especially being the system charged a careful analysis of phase separation is needed [26].

It has been recently emphasized [15] that there is a close connection between the doping dependent incom m ensurability as discussed above and the chemical potential in cuprates. In fact the chem ical potential for the elec- $(e_h + x \frac{\partial e_h}{\partial x})$. From trons can be related to e_h via: = Fig. 3(b) one can then deduce that is approximately constant for x < 0:1 and decreases for x > 0:1 in qualitative agreem ent with the observed behavior [14, 15]. The rate of change of with doping, being a high derivative of the energy, is very sensitive to nite size e ects and, m oreover, few experimental points are available in this doping range in order to allow for a precise com parison. A rough estimate indicates that the theoretical rate of change of with doping for x > 1=8 is approximately a factor of 2 larger than the experim entalone [14, 15]. This m ay be due to phase separation among the d = 4 stripe solution and the param agnetic overdoped Ferm i liquid as mention above.

We nally turn to the discussion of our calculation in light of recent m easurem ents of the Hall coe cient R_{H} in LNSCO [16] and YBCO [17]. In the form $er com pound R_{H}$ displays an abrupt decrease below the charge-stripe ordering tem perature T₀ and for concentrations x = 1=8. It has convincingly been argued that quasi 1D transport is not enough to explain this anom aly and instead re ects a rem arkable cancellation due to particle-hole sym m etry in the stripe state [17, 29]. A partial suppression of R_{H} (and simultaneously the therm opower S) below some tem perature T_{max} has also been observed in YBCO up to oxygen contents corresponding to doping x 1=8 [17]. For distant stripes we indeed observe that the chem ical potential crosses an approximately particle-hole symmetric band (see Fig. 2). Interstripe hopping becomes signi cant for x > 0:1 how ever it does not break particle-hole sym m etry. As discussed above the chem ical potential shifts from the center of the band for x > 1=8, thus breaking particle-hole sym m etry and consequently both R $_{\rm H}\,$ and S start to grow in modulus. Unfortunately the magnitude and even the sign of the transport coe cients cannot be predicted by a know ledge of the band structure alone. For example R_H for our Ferm i surface (which turns out to be open) is determ ined by the unknown anisotropy of the scattering path length [30].

To conclude we have shown that, contrary to widespread believe, an appropriate mean-eld theory of

stripe phases in cuprates is not in contradiction with experiments. Our theory explains in a simple way the change of behavior of several experim ental quantities (incom m ensurability, chem ical potential, transport coe cients) around the \mbox{m} agic" doping x = 1=8. Obviously the present stripes are static w hereas those in realm aterials are dynam ic unless pinned by a structural distortion. M any properties how ever will be largely independent of the dynamical or static character of the stripes. The energy for example is determined by short range correlations and is insensitive to the long-distant behavior. This is analogous to the problem of spin waves in a 1D antiferrom agnet where the spin wave approxim ation gives a reasonable value for the energy although the system does not have true long-range order[31]. Since the properties we have discussed are mainly determined by the energetics we believe that the present mean-eld theory is a good starting point for an understanding of the electronic structure of hole doped cuprates.

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